

### **Features**

- Excellent Gate Charge x R<sub>DS(on)</sub> Product(FOM)
- Very Low On-Resistance R<sub>DS(on)</sub>
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## **Maximum Ratings**

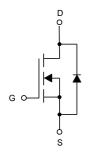
- Operating Junction Temperature Range : -55°C to +175°C
- Storage Temperature Range: -55°C to +175°C
- Thermal Resistance: 2.2°C/W Junction to Case<sup>(Note 1)</sup>

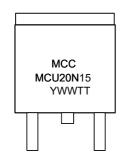
Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V <sub>DS</sub>	150	V
Gate-Source Volltage		V <sub>GS</sub>	±20	V
Continuous Drain Current	T <sub>C</sub> =25°C	1	20	Α
	T <sub>C</sub> =100°C	l <sub>D</sub>	14	Α
Pulsed Drain Current		I <sub>DM</sub>	80	Α
Single Pulse Avalanche Energy (Note 2)		E <sub>AS</sub>	65	mJ
Total Power Dissipation		P <sub>D</sub>	68	W

Note: 1. Surface Mounted on FR4 Board, t ≤ 10 sec.

2. EAS Condition :  $T_J=25^{\circ}C$ ,  $V_{DD}=50V$ ,  $V_G=10V$ , L=0.5mH,  $R_a=25\Omega$ .

# ⇒bh/fbU 'Ghfi Whi fY'UbX'A Uf\_]b[ '7 cXY

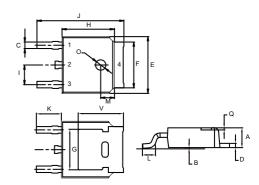




YWWTT: 5 codes in total Y is the year WW is the cycle TT is the line type

# N-CHANNEL MOSFET

# DPAK(TO-252)



- 1. Gate
- 2,4. Drain
  - 3. Source

	DIMENSIONS				
DIM	INC	INCHES		IM	NOTE
DIIVI	MIN	MAX	MIN	MAX	INOTE
Α	0.087	0.094	2.20	2.40	
В	0.000	0.005	0.00	0.13	
С	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
E	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
Н	0.236	0.244	6.00	6.20	
I	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.114		2.90		TYP.
L	0.055	0.067	1.40	1.70	
М	0.063		1.60		TYP.
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.35		TYP.



# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

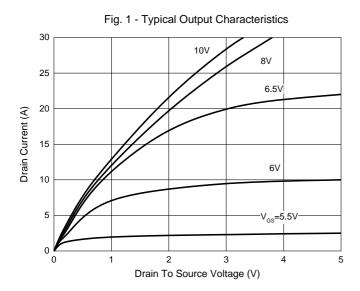
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	150			V
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =150V, V <sub>GS</sub> =0V			1	μA
Gate-Threshold Voltage <sup>(Note 3)</sup>	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.5	3.3	4.5	V
Drain-Source On-Resistance <sup>(Note 3)</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =10A		59	65	mΩ
Forward tranconductance <sup>(Note 3)</sup>	<b>g</b> <sub>FS</sub>	V <sub>DS</sub> =5V, I <sub>D</sub> =10A	15			S
Dynamic Characteristics(Note 4)						
Input Capacitance	C <sub>iss</sub>			600		
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =75V, $V_{GS}$ =0V,f=1MHz		74.7		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			10.8		
Total Gate Charge	Qg			12		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =75V, $V_{GS}$ =10V, $I_{D}$ =10A		5.7		nC
Gate-Drain Charge	$Q_{gd}$			2.7		
Turn-On Delay Time	t <sub>d(on)</sub>			9.5		
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =75V, R <sub>L</sub> =7.5 $\Omega$		5.5		no
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =3 $\Omega$		12.5		- ns
Turn-Off Fall Time	t <sub>f</sub>			3		
Drain-Source Body Diode Cha	racteristi	cs				
Continuous Body Diode Current	Is	T <sub>C</sub> =25°C			20	Α
Body Diode Voltage (Note 3)	V <sub>SD</sub>	I <sub>SD</sub> =10A, V <sub>GS</sub> =0V			1.2	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =I <sub>S</sub> ,di/dt=100A/μs		29		ns
Reverse Recovery Charge	Q <sub>rr</sub>	1- 18,αναι-100/νμο		130		nC

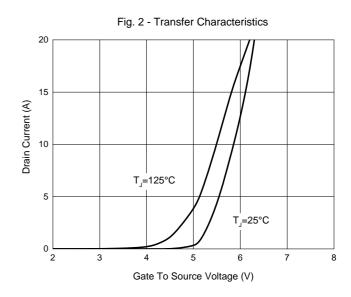
Note 3. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤2%.

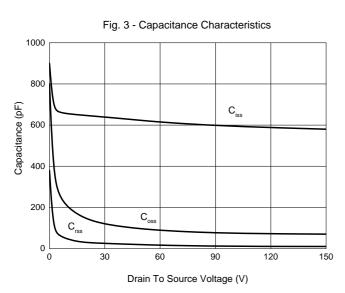
4. Guaranteed by Design, Not Subject to Production Testing.

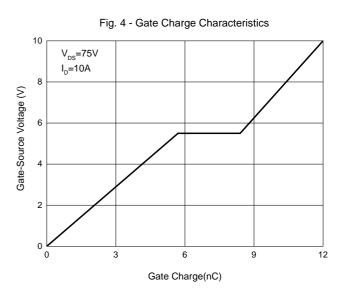


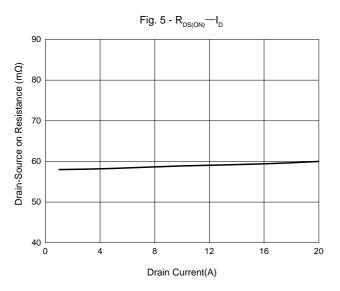
## **Curve Characteristics**

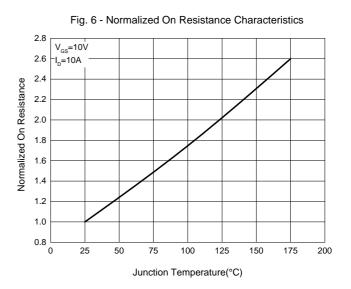














## **Ordering Information**

Device	Packing	
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel	

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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